· # 10-15-4

PATENT APPLICATION

Group Art Unit: UNKNOWN

Examiner: UNKNOWN

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Hiroyuki NAGASAWA

Appln. No. UNKNOWN

Confirmation No.:UNKNOWN

Filed: August 09, 2001

3d. 11ugust 05, 2001

SILICON CARBIDE AND METHOD OF MANUFACTURING THE SAME

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §§ 1.97 and 1.98

Commissioner for Patents Washington, D.C. 20231

Sir:

For:

In accordance with the duty of disclosure under 37 C.F.R. § 1.56, Applicant hereby notifies the U.S. Patent and Trademark Office of the documents which are listed on the attached Form PTO-1449 and/or listed herein and which the Examiner may deem material to patentability of the claims of the above-identified application.

One copy of each of the listed documents is submitted herewith.

The present Information Disclosure Statement is being filed: (1) No later than three months from the application's filing date for an application other than a continued prosecution application (CPA) under §1.53(d); and therefore, no Statement under 37 C.F.R. § 1.97(e) or fee under 37 C.F.R. § 1.17(p) is required.

In compliance with the concise explanation requirement under 37 C.F.R. § 1.98(a)(3) for foreign language documents, Applicant submits the following explanations:

Japanese Unexamined Patent Publication Nos. Hei 12-068225 and 11-503571 are discussed beginning at page 3 of the specification.

Japanese Unexamined Patent Publication Nos. Hei 11-121393 and 09-063968 are discussed beginning at page 4 of the specification.



INFORMATION DISCLOSURE STATEMENT U.S. Appln. No.

Japanese Unexamined Patent Publication No. Hei 10-507734 is discussed beginning at page 5 of the specification.

The submission of the listed documents is not intended as an admission that any such document constitutes prior art against the claims of the present application. Applicant does not waive any right to take any action that would be appropriate to antedate or otherwise remove any listed document as a competent reference against the claims of the present application.

Respectfully submitted,

Alan J. Kasper

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Date: August 9, 2001

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Form PTO-1449 (Rev. 2-32)			Q65781	Confirm			
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)			Applicant: Hiroyuki NAGASAWA				
			Filing Date: August 09, 2001	Group: UNKN(Group: UNKNOWN		
U.S. PATENT DOCUMENTS							
Examiner Initial	Document Number	Date	Name	Class	Sub- Class	Filing Date (if appropriate)	
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	Document	Date	Country	Class	Sub- class	Translation Yes/No	
	2000-68225	3/3/2000	Japan			No	
	11-503571 11-121393	3/26/99 4/30/99	Japan Japan			No No	
	9-63968	3/7/97	Japan			No	
	10-507734	7/28/98	Japan			No	
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	OTHER DOCUME	NITTO (I. I. I.	A 1 771 D D				
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	D. Larkin, et al, Site-Competition Epitaxy for Superior Silicon Carbide Electronics, Applied Physics Letter 65, September 26, 1994,						
	3eptember 20, 1994,						
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EXAMINER:			DATE CONSIDERE	D:			
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